WESTCODE

An **IXYS** Company

Rectifier Diode
Types W1520N#500 to W1520N#600
Old Part No.: SW46-58CXC620

Absolute Maximum Ratings

	VOLTAGE RATINGS	MAXIMUM LIMITS	UNITS
V_{RRM}	Repetitive peak reverse voltage, (note 1)	5000-6000	V
V_{RSM}	Non-repetitive peak reverse voltage, (note 1)	5100-6100	V

	OTHER RATINGS	MAXIMUM LIMITS	UNITS
$I_{F(AV)M}$	Maximum average forward current, T_{sink}=55°C, (note 2)	1478	A
$I_{F(AV)M}$	Maximum average forward current. T_{sink}=100°C, (note 2)	1001	A
$I_{F(AV)M}$	Maximum average forward current. T_{sink}=100°C, (note 3)	639	A
$I_{F(RMS)M}$	Nominal RMS forward current, T_{sink}=25°C, (note 2)	2727	A
$I_{F(d.c.)}$	D.C. forward current, T_{sink}=25°C, (note 4)	2492	A
I_{FSM}	Peak non-repetitive surge t_p=10ms, V_{rm}=60%V_{RRM}, (note 5)	12.0	kA
I_{FSM2}	Peak non-repetitive surge t_p=10ms, V_{rm}≤10V, (note 5)	13.2	kA
I^2t	I^2t capacity for fusing t_p=10ms, V_{rm}=60%V_{RRM}, (note 5)	720×10³	A²s
I^2t	I^2t capacity for fusing t_p=10ms, V_{rm}≤10V, (note 5)	871×10³	A²s
$T_{j\ op}$	Operating temperature range	-40 to +150	°C
T_{stg}	Storage temperature range	-55 to +160	°C

Notes:-
1) De-rating factor of 0.13% per °C is applicable for T_j below 25°C.
2) Double side cooled, single phase; 50Hz, 180° half-sinewave.
3) Single side cooled, single phase; 50Hz, 180° half-sinewave.
4) Double side cooled.
5) Half-sinewave, 150°C T_j initial.

Characteristics

	PARAMETER	MIN.	TYP.	MAX.	TEST CONDITIONS (Note 1)	UNITS
V_{FM}	Maximum peak forward voltage	-	-	2.20	I_{TM}=2340A	V
V_{FM}	Maximum peak forward voltage	-	-	3.33	I_{TM}=4400A	V
V_{T0}	Threshold voltage	-	-	0.904		V
r_T	Slope resistance	-	-	0.552		mΩ
I_{RRM}	Peak reverse current	-	-	70	Rated V_{RRM}	mA
Q_{rr}	Recovered charge	-	7200	-		μC
Q_{ra}	Recovered charge, 50% Chord	-	3350	3600	I_{TM}=1000A, t_p=2000μs, di/dt=10A/μs, V_r=100V	μC
I_{rm}	Reverse recovery current	-	160	-		A
t_{rr}	Reverse recovery time	-	42	-		μs
R_{thJK}	Thermal resistance, junction to heatsink	-	-	0.022	Double side cooled	K/W
		-	-	0.044	Single side cooled	K/W
F	Mounting force	19	-	26		kN
W_t	Weight	-	480	-		g

Notes:-

1) Unless otherwise indicated T_j=150°C.
2) For other clamp forces, please consult factory.

Notes on rupture rated packages.
This product is available with a non-rupture rated package. For additional details on these products, please consult factory.

Notes on Ratings and Characteristics

1.0 Voltage Grade Table

Voltage Grade	V_{RRM} V	V_{RSM} V	V_R DC V
50	5000	5100	2200
52	5200	5300	2240
54	5400	5500	2280
56	5600	5700	2320
58	5800	5900	2360
60	6000	6100	2400

2.0 Extension of Voltage Grades

This report is applicable to other voltage grades when supply has been agreed by Sales/Production.

3.0 De-rating Factor

A blocking voltage de-rating factor of 0.13%/°C is applicable to this device for T_j below 25°C.

4.0 Snubber Components

When selecting snubber components, care must be taken not to use excessively large values of snubber capacitor or excessively small values of snubber resistor. Such excessive component values may lead to device damage due to the large resultant values of snubber discharge current. If required, please consult the factory for assistance.

5.0 Computer Modelling Parameters

5.1 Device Dissipation Calculations

$$I_{AV} = \frac{-V_{T0} + \sqrt{V_{T0}^2 + 4 \cdot ff^2 \cdot r_T \cdot W_{AV}}}{2 \cdot ff^2 \cdot r_T}$$ and:
$$W_{AV} = \frac{\Delta T}{R_{th}}$$
$$\Delta T = T_{j\max} - T_K$$

Where V_{T0}=0.904V, r_T=0.552mΩ,

R_{th} = Supplementary thermal impedance, see table below and

ff = Form factor, see table below.

Supplementary Thermal Impedance				
Conduction Angle	6 phase (60°)	3 phase (120°)	½ wave (180°)	d.c.
Square wave Double Side Cooled	0.0285	0.0255	0.0240	0.0220
Square wave Single Side Cooled	0.0513	0.0484	0.0469	0.0440
Sine wave Double Side Cooled	0.0257	0.0233	0.0220	
Sine wave Single Side Cooled	0.0482	0.0463	0.0440	

Form Factors				
Conduction Angle	6 phase (60°)	3 phase (120°)	½ wave (180°)	d.c.
Square wave	2.449	1.732	1.414	1
Sine wave	2.778	1.879	1.57	

5.2 Calculating V_F using ABCD Coefficients

The on-state characteristic I_F vs. V_F, on page 6 is represented in two ways;
(i)   the well established V_{T0} and r_T tangent used for rating purposes and
(ii)   a set of constants A, B, C, D, forming the coefficients of the representative equation for V_F in terms of I_F given below:

$$V_F = A + B \cdot \ln(I_F) + C \cdot I_F + D \cdot \sqrt{I_F}$$

The constants, derived by curve fitting software, are given below for both hot and cold characteristics. The resulting values for V_F agree with the true device characteristic over a current range, which is limited to that plotted.

	25°C Coefficients	160°C Coefficients
A	0.2752955	-0.5382763
B	0.1242329	0.2918416
C	3.472×10^{-4}	6.499×10^{-4}
D	-4.4595×10^{-3}	-0.0216334

5.3 D.C. Thermal Impedance Calculation

$$r_t = \sum_{p=1}^{p=n} r_p \cdot \left(1 - e^{\frac{-t}{\tau_p}} \right)$$

Where $p = 1$ to n, n is the number of terms in the series and:
- t = Duration of heating pulse in seconds.
- r_t = Thermal resistance at time t.
- r_p = Amplitude of p_{th} term.
- τ_p = Time Constant of r_{th} term.

The coefficients for this device are shown in the tables below:

D.C. Single Side Cooled					
Term	1	2	3	4	5
r_p	0.0291698	4.295845×10^{-3}	7.57109×10^{-3}	2.195801×10^{-3}	1.628753×10^{-3}
τ_p	5.67822	1.123602	0.1407857	0.014381914	1.272749×10^{-3}

D.C. Double Side Cooled				
Term	1	2	3	4
r_p	0.01177146	6.485814×10^{-3}	2.471007×10^{-3}	1.607109×10^{-3}
τ_p	0.9495346	0.1337950	0.01636628	1.255571×10^{-3}

6.0 Reverse recovery ratings

(i) Q_{ra} is based on 50% I_{rm} chord as shown in Fig. 1
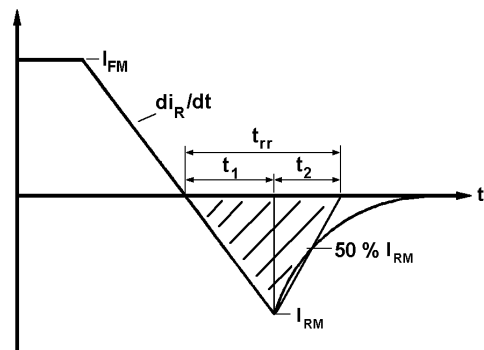
Fig. 1

(ii) Q_{rr} is based on a 150µs integration time i.e.

$$Q_{rr} = \int_0^{150\mu s} i_{rr}.dt$$

(iii)

$$K\ Factor = \frac{t_1}{t_2}$$

Curves

Figure 1 - Forward characteristics of Limit device
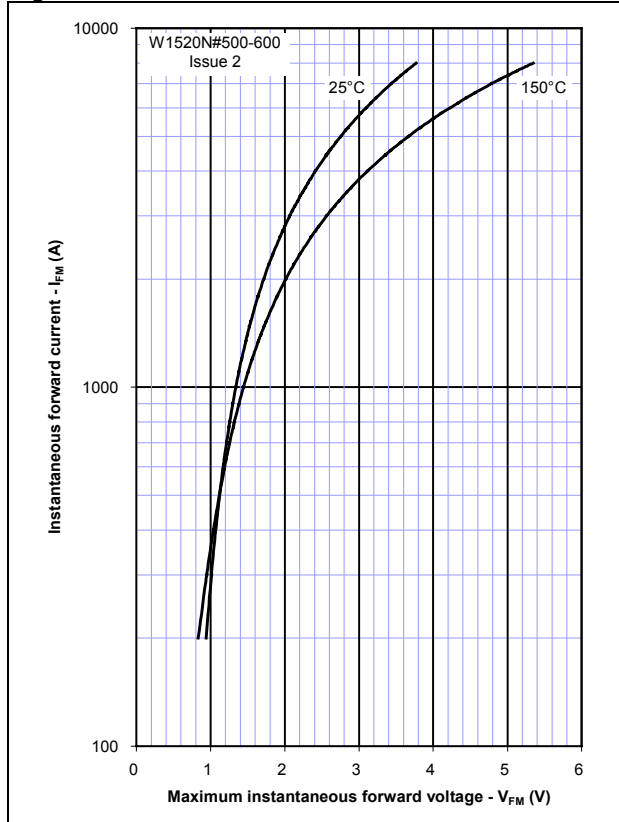
Figure 2 - Transient thermal impedance
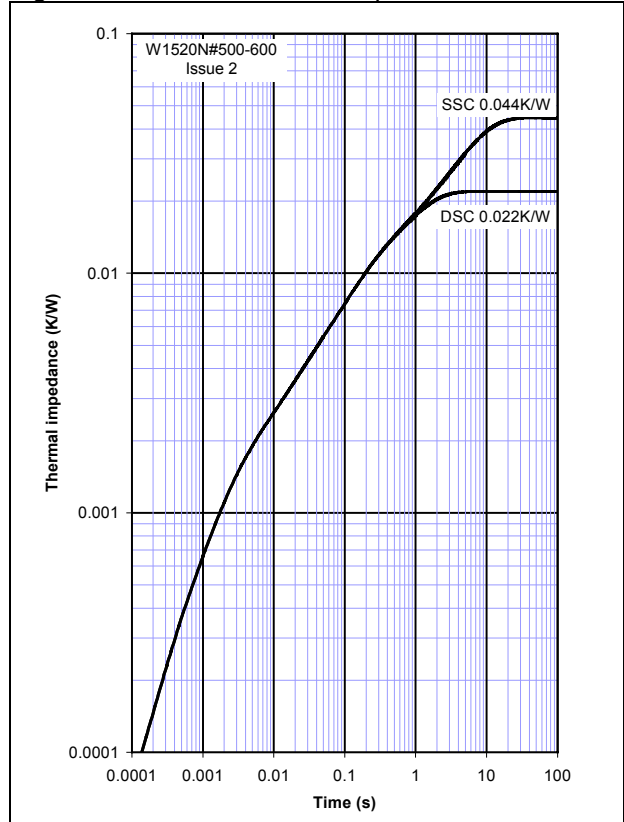
Figure 3 - Maximum Surge Rating
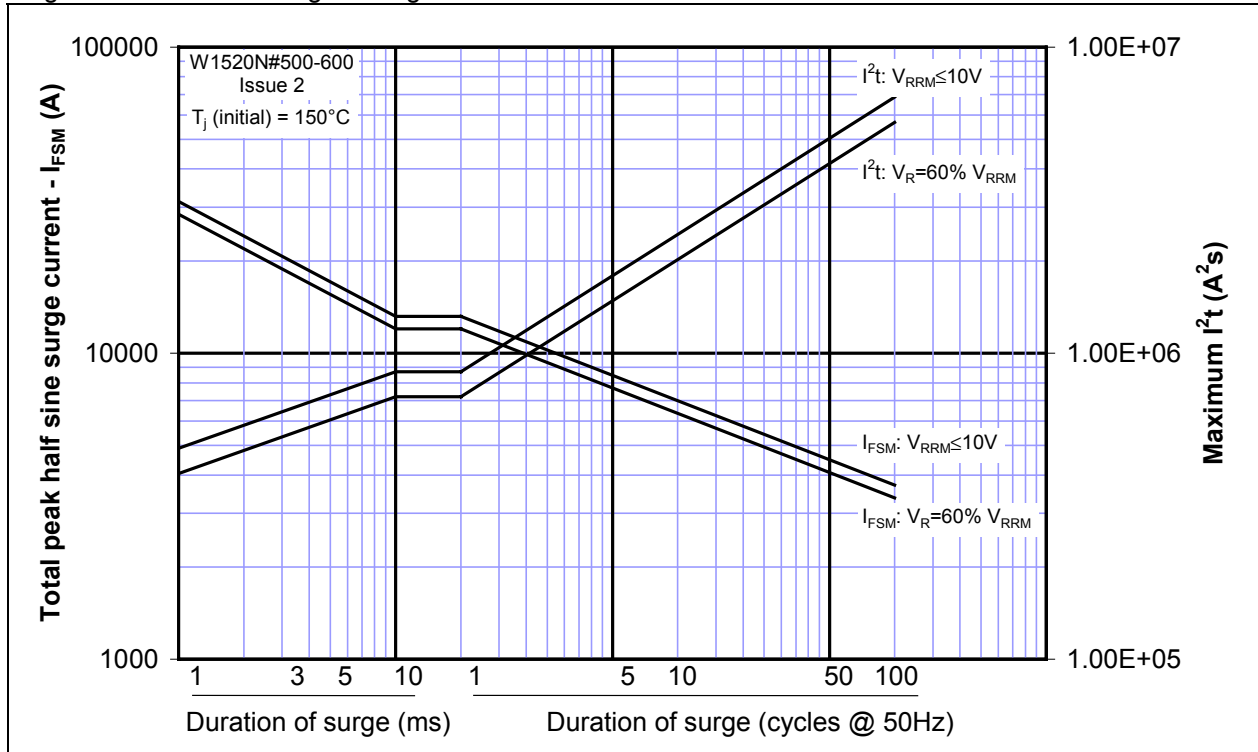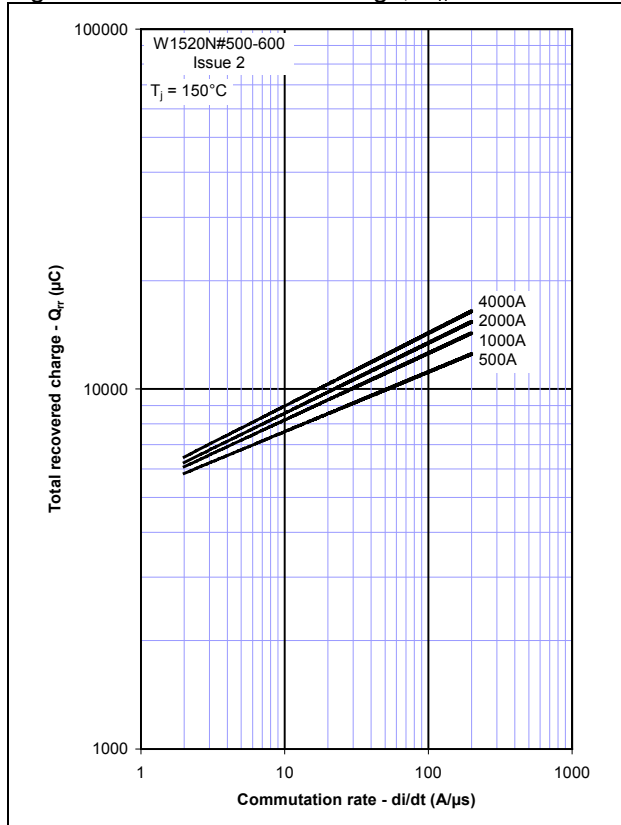
Figure 4 - Total recovered charge, Q$_{rr}$

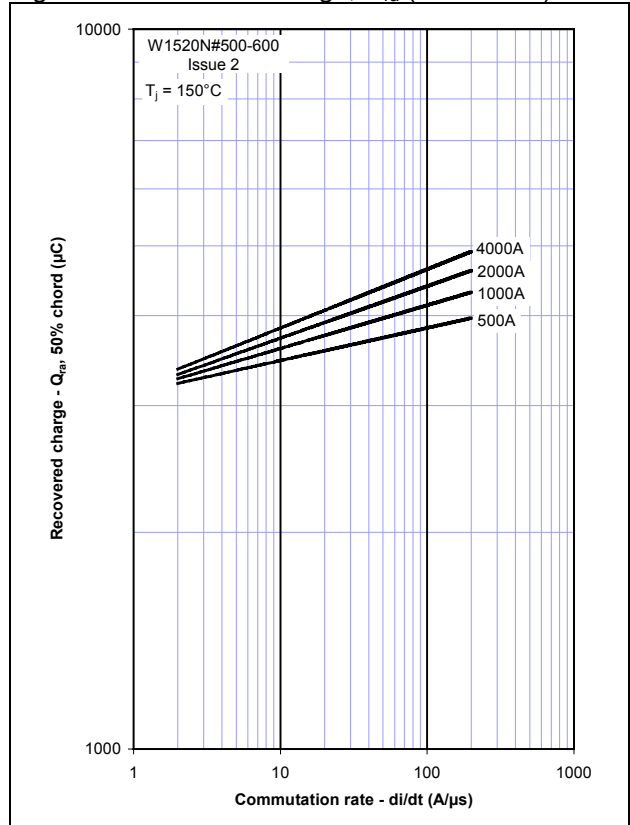Figure 5 - Recovered charge, Q$_{ra}$ (50% chord)

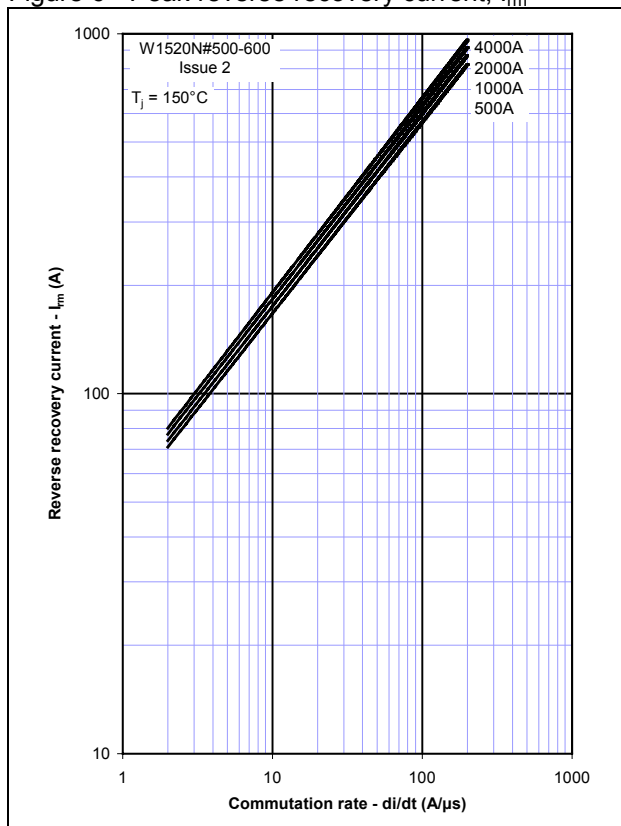

Figure 6 - Peak reverse recovery current, I$_{rm}$
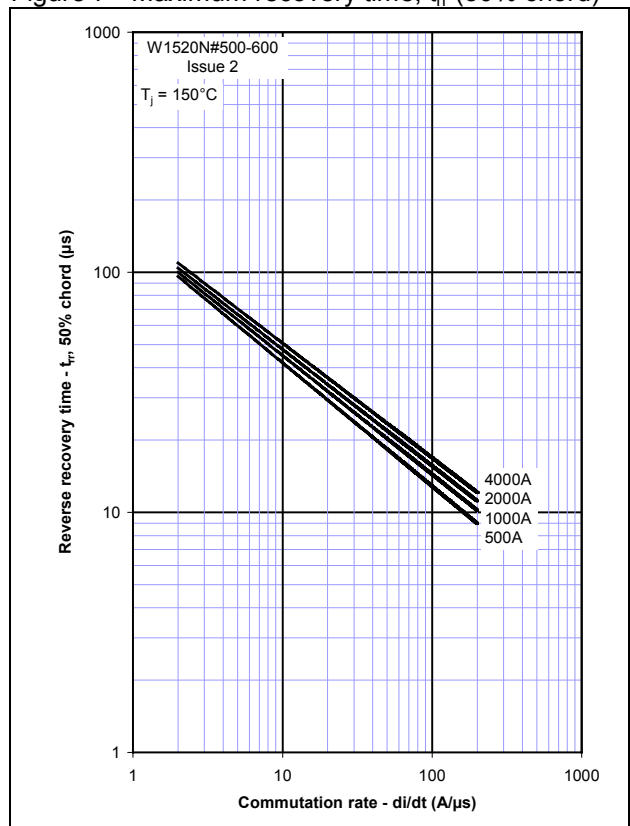

Figure 7 - Maximum recovery time, t$_{rr}$ (50% chord)

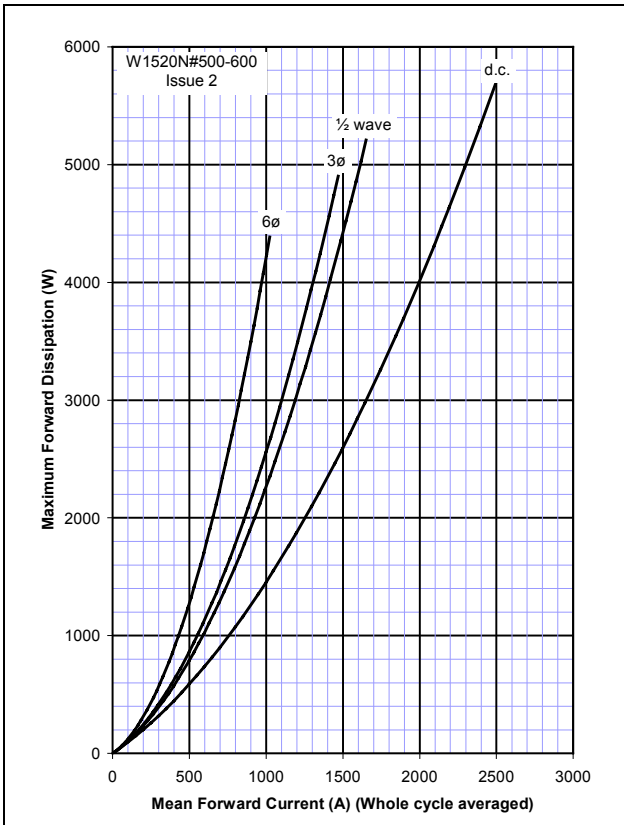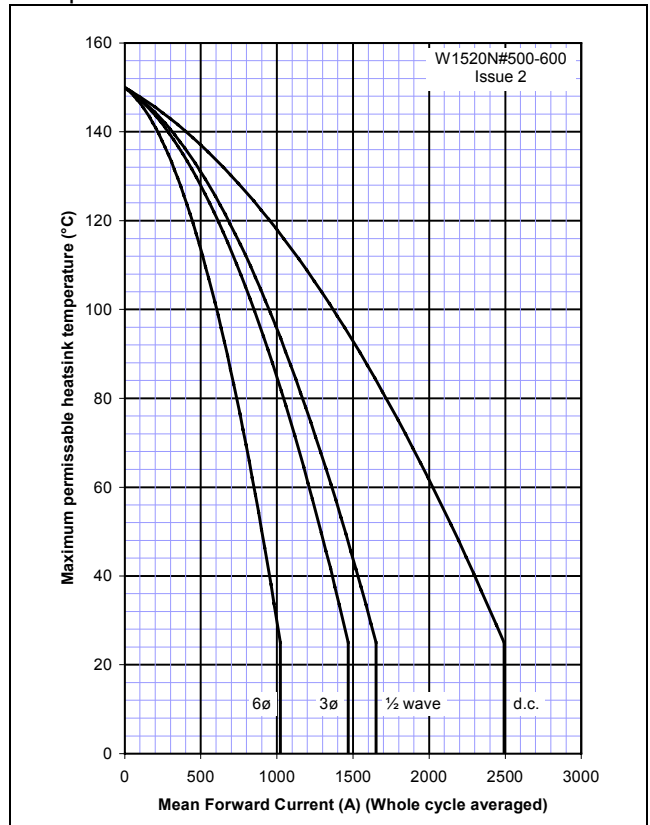Figure 8 – Forward current vs. Power dissipation –
Double Side Cooled

Figure 9 – Forward current vs. Heatsink
temperature - Double Side Cooled

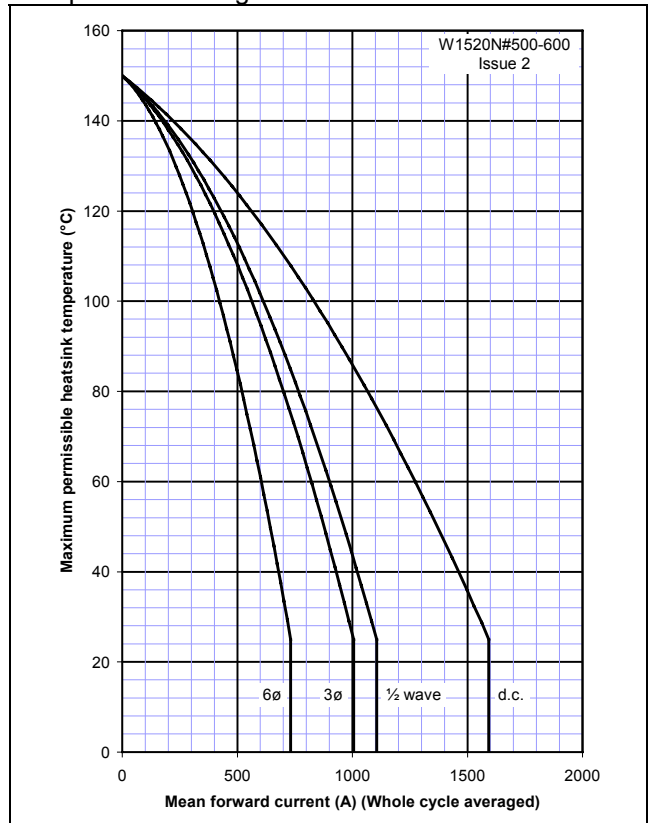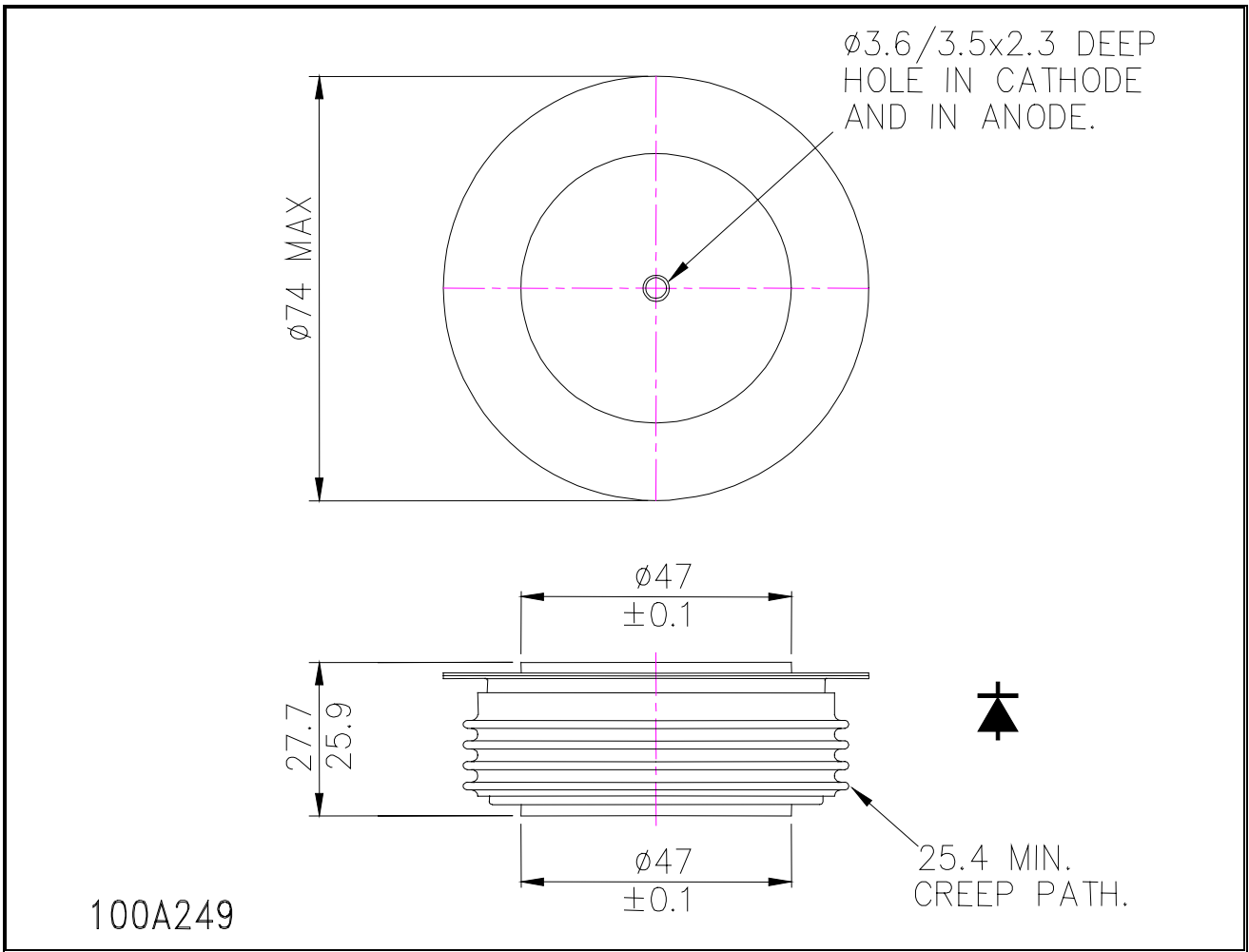Figure 10 – Forward current vs. Power dissipation
– Single Side Cooled
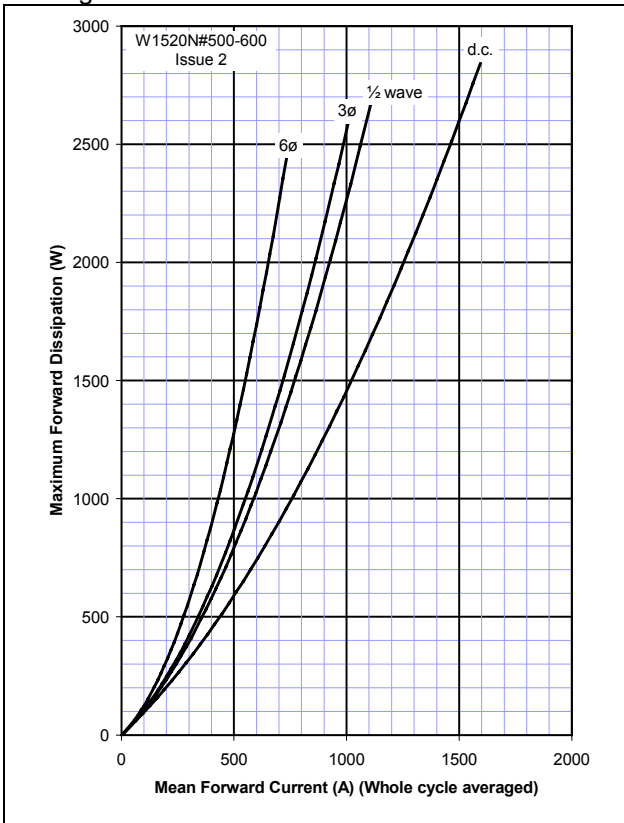
Figure 11 – Forward current vs. Heatsink
temperature – Single Side Cooled

Outline Drawing & Ordering Information

Ø3.6/3.5x2.3 DEEP HOLE IN CATHODE AND IN ANODE.

Ø74 MAX

Ø47 ±0.1

27.7
25.9

Ø47 ±0.1

25.4 MIN. CREEP PATH.

100A249

ORDERING INFORMATION   (Please quote 10 digit code as below)

W1520	N#	◆◆	0
Fixed Type Code	Outline code NC = 27.7mm Clamp height capsule NT = 27.7mm Clamp height, rupture rated capsule	Voltage code V$_{RRM}$/100 50-60	Fixed code

Typical order code: W1520NT500 – 5000V V$_{RRM}$, 27.7mm clamp height.

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